## NSN 5961-01-317-9377

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-317-9377 **Inclosure Material:** Ceramic or glass or metal **Overall Length:** Between 0.120 inches and 0.200 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.060 inches and 0.090 inches **Function For Which Designed:** Microwave **End Application:** Strategic weapon systems (poseidon and trident). General purpose electronic test equipment (gpete). Calibration standards equipment. **Mounting Method: Terminal Criticality Code Justification: Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 35.0 breakdown voltage, dc **Current Rating Per Characteristic:** 100.00 nanoamperes forward current, average peak **Power Rating Per Characteristic:** 400.0 watts small-signal input power, common-collector absolute **Special Features:** Weapon system essential; junction pattern arrangement: pin **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: